



DTC123EET1G Information



For Reference Only

Part Number DTC123EET1G

Manufacturer ON Semiconductor

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single, Pre-Biased

Description TRANS PREBIAS NPN 200MW SC75

Package SC-75, SOT-416

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









DTC123EET1G Specifications

	Report errors?
Supplier Device Package	SC-75, SOT-416
Package / Case	SC-75, SOT-416
Mounting Type	Surface Mount
Power - Max	200mW
Frequency - Transition	-
Current - Collector Cutoff (Max)	500nA
Vce Saturation (Max) @ Ib, Ic	250mV @ 5mA, 10mA
DC Current Gain (hFE) (Min) @ Ic, Vce	8 @ 5mA, 10V
Resistor - Emitter Base (R2) (Ohms)	2.2k
Resistor - Base (R1) (Ohms)	2.2k
Voltage - Collector Emitter Breakdown (Max)	50V
Current - Collector (Ic) (Max)	100mA
Transistor Type	NPN - Pre-Biased
Series	-
Package	SC-75, SOT-416
	Transistors - Bipolar (BJT) - Single, Pre-Biased
Category	Discrete Semiconductor Products
Manufacturer	ON Semiconductor
Manufacturer Part Number	DTC123EET1G

DTC123EET1G Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

DTC123EET1G Payment Methods



















DTC123EET1G Shipping Methods













If you have any question about DTC123EET1G, please do not hesitate to contact us!

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